

Rev. V1

#### **Features**

High Gain: 27.5 dBP1dB: 33 dBmP3dB: 34 dBm

IM3 Level: -40 dBc @ Pout = +20 dBm/tone
Power Added Efficiency: 28% @ P3dB
Temperature Compensated Output Power

Detector

Lead-Free 5 mm AQFN 32-lead Package

RoHS\* Compliant

## **Applications**

Point-to-Point

VSAT

## **Description**

The MAAP-011362 is a 2 W, 4-stage power amplifier assembled in a lead-free 5 mm 32-lead air cavity QFN plastic package. This power amplifier operates from 27.5 to 30 GHz and provides 27.5 dB of linear gain, 2 W saturated output power and 28% efficiency while biased at 5.5 V.

The MAAP-011362 can be used as a power amplifier stage or as a driver stage in higher power applications. This device is ideally suited for VSAT and 28 GHz PTP applications.

For enhanced linearity at higher output power, the drain current can be increased

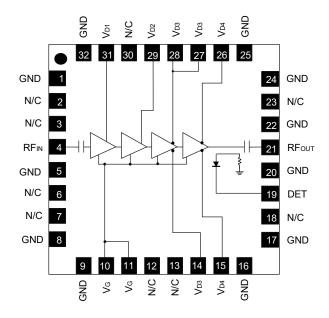
This product is fabricated using a GaAs pHEMT process which features full passivation for enhanced reliability.

# Ordering Information<sup>1,2</sup>

Part Number	Package
MAAP-011362-TR0500	500 Part Reel
MAAP-011362-001SMB	Sample Board

- 1. Reference Application Note M513 for reel size information.
- 2. All sample boards include 3 loose parts.

## **Functional Schematic**



# Pin Configuration<sup>3,4</sup>

Pin #	Pin Name	Description
1, 5, 8, 9, 16, 17, 20, 22, 24, 25, 32	GND	Ground
2, 3 , 6, 7, 12, 13, 18, 23, 30	N/C	No Connection
4	RF <sub>IN</sub>	RF Input
10, 11	$V_{G}$	Gate Voltage
14, 27, 28	$V_{D3}$	Drain Voltage 3
15, 26	$V_{D4}$	Drain Voltage 4
19	DET	Power Detector
21	RF <sub>OUT</sub>	RF Output
29	$V_{D2}$	Drain Voltage 2
31	V <sub>D1</sub>	Drain Voltage 1

- MACOM recommends connecting all No Connection (N/C) pins to ground.
- The exposed pad centered on the package bottom must be connected to RF, DC and thermal ground.

<sup>\*</sup> Restrictions on Hazardous Substances, compliant to current RoHS EU directive.



Rev. V1

## Electrical Specifications: $T_A = +25^{\circ}C$ , $V_D = 5.5 V$ , $Z_0 = 50 \Omega$

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Gain	27.5 GHz 30.0 GHz	dB	24.2 21.3	27.5 27.5	_
Output Power @ 3dB	27.5 GHz 30.0 GHz	dBm	31.5 31	34.0 34.5	_
IM3 Level	P <sub>OUT</sub> = 20 dBm / tone	dBc	_	-40	_
Power Added Efficiency @ 3dB	_	%	_	28	_
Input Return Loss	_	dB	_	15	_
Output Return Loss	_	dB	_	15	_
Quiescent Current <sup>5</sup>	I <sub>DSQ</sub> (see bias conditions, page 4)	mA	_	1200	_
Drain Current ( $V_{D1} + V_{D2} + V_{D3} + V_{D4}$ )	P <sub>IN</sub> = 12 dBm	mA		1700	_

<sup>5.</sup> Quiescent current can be increased to optimize the IM3 performance at output power close to saturation. Please see the application information section of this datasheet

## **Maximum Operating Conditions**

Parameter	Rating
Input Power	P <sub>IN</sub> ≤3 dB Compression
Junction Temperature <sup>6,7</sup>	+160°C
Operating Temperature	-40°C to +85°C

- 6. Operating at nominal conditions with junction temperature
- ≤ +160°C will ensure MTTF > 1 x 10<sup>6</sup> hours.
   Junction Temperature (T<sub>J</sub>) = T<sub>C</sub> + Θ<sub>JC</sub> \* ((V \* I) (P<sub>OUT</sub> P<sub>IN</sub>)) Typical thermal resistance (Θ<sub>JC</sub>) = 7 °C/W. a) For  $T_C = +25^{\circ}C$

 $T_J = 78.9$ °C @ 6 V, 1.7 A,  $P_{OUT} = 34.0$  dBm,  $P_{IN} = 12$  dBm b) For  $T_C = +85^{\circ}C$ 

 $T_J = 138.9$ °C @ 6 V, 1.7 A,  $P_{OUT} = 34.0$  dBm,  $P_{IN} = 12$  dBm

# **Handling Procedures**

Please observe the following precautions to avoid damage:

## **Static Sensitivity**

electronic devices are sensitive electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these HBM Class 1A devices.

# **Absolute Maximum Ratings**<sup>8,9,10</sup>

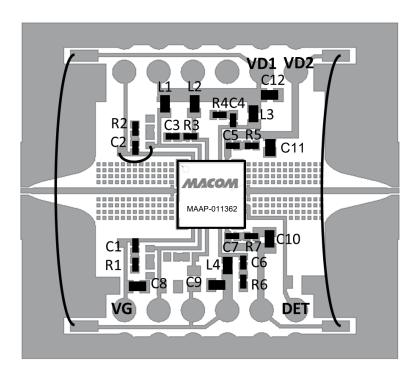
Parameter	Absolute Maximum	
Input Power	15 dBm	
Drain Voltage	+6 V	
Gate Voltage	-3 to 0 V	
Junction Temperature <sup>9</sup>	+175°C	
Storage Temperature	-65°C to +125°C	

- 8. Exceeding any one or combination of these limits may cause permanent damage to this device.
- MACOM does not recommend sustained operation near these survivability limits.
- 10. Junction temperature directly affects device MTTF. Junction temperature should be kept as low as possible to maximize lifetime.

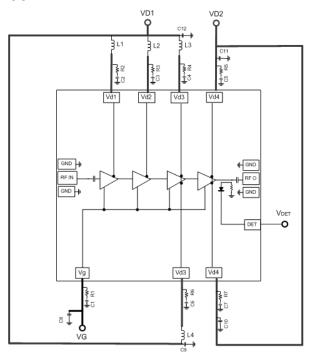


Rev. V1

# **Sample Board Layout**



## **Application Schematic**



## **Parts List**

Part	Value	Case Style
C1 - C7	0.01 μF	0402
C8 - C12	22 µF	0603
R1 - R7	10 Ω	0402
L1 - L4	Ferrite bead Murata BLM18HE601SN1D	0603

## **Sample Board Material Specifications**

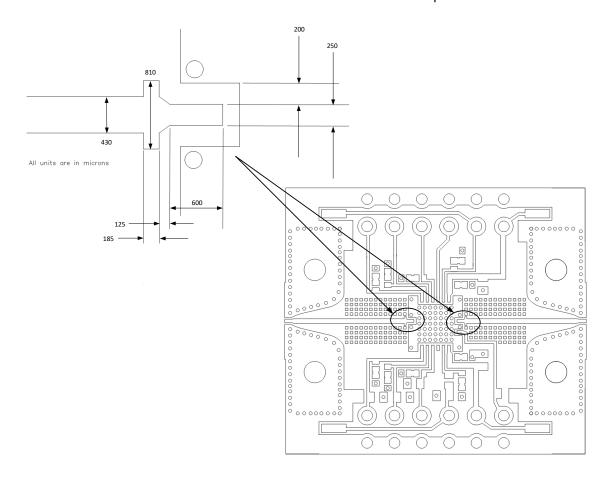
Top Layer: 1/2 oz Copper Cladding, 0.017 mm thickness Dielectric Layer: Rogers RO4003C 0.203 mm thickness Bottom Layer: 1/2 oz Copper Cladding, 0.017 mm thickness Finished overall thickness: 0.238 mm



Rev. V1

## **Recommended PCB Layout Detail:**

RF input and output pre-matching circuit patterns are identical and are designed to compensate packaging effects. Transmission line dimensions apply to a PCB with 0.203 mm thick Rogers RO4003C laminate dielectric. Performance curves shown in this data sheet were measured with these circuit patterns.



# **Biasing Conditions**

Recommended biasing conditions are  $V_D = 5.5 \text{ V}$ ,  $I_{DSQ} = 1.2$  to 1.8 A (controlled with  $V_G$ ). The drain bias voltage range is 5.0 to 5.5 V. Higher  $I_{DSQ}$  leads to improved IM3 performance close to  $P_{SAT}$ .

 $V_{\rm G}$  pins 10 and 11 are connected internally; choose either pin for layout convenience. Muting can be accomplished by setting the  $V_{\rm G}$  to the pinched off voltage ( $V_{\rm G}$  = -2 V).

 $V_D$  bias must be applied to  $V_D1$ ,  $V_D2$ ,  $V_D3$ , and  $V_D4$  pins.  $V_D3$  pins 27 and 28 are connected internally: choose pin 14, 27 or 28 for layout convenience. Two  $V_D4$  pins 15 and 26 (not connected internally) are required for current symmetry.

# Operating the MAAP-011362

#### Turn-on

- 1. Apply V<sub>G</sub> (-1.5 V).
- 2. Apply V<sub>D</sub> (5.5 V typical).
- 3. Set  $I_{DQ}$  by adjusting Vg more positive (typically -0.9 to -1.0 V for  $I_{DSQ}$  = 1.2 A).
- 4. Apply RF<sub>IN</sub> signal.

#### Turn-off

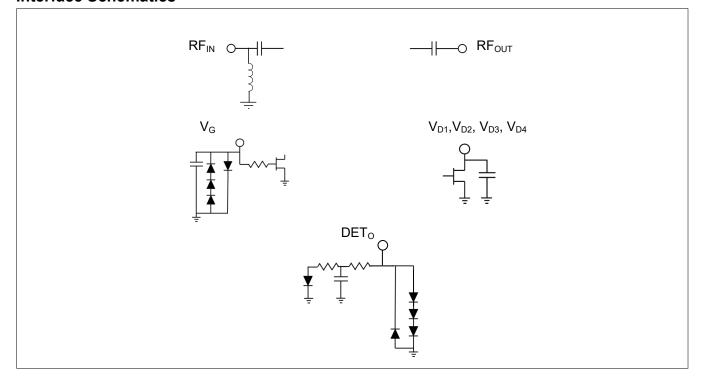
- 1. Remove RFIN signal.
- 2. Decrease V<sub>G</sub> to -1.5 V.
- 3. Decrease V<sub>D</sub> to 0 V.

4



Rev. V1

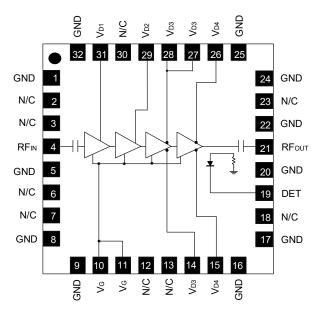
## **Interface Schematics**





Rev. V1

# **Pin Configuration and Functional Descriptions**



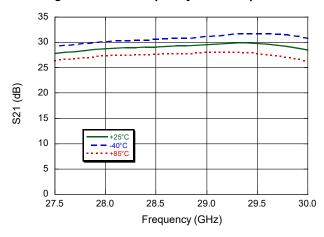
Pin#	Pin Name	Description
1,5,8,9,16,17, 20,22,24,25,32	GND	These pins are grounded on the package and MMIC.
2,3,6,7,12,13, 18,23,30	N/C	These pins are not connected to anything and are recommended to be grounded in the application.
4	RF <sub>IN</sub>	RF Signal Input. This pin is matched to 50 $\Omega$ and is AC coupled.
10,11	V <sub>G</sub>	Power amplifier gate controls. Adjust $V_G$ from $-1.5~V$ to $0~V$ to achieve the desired quiescent current. External bypass capacitors and de-Q resistor are required as described in the applications schematic.
14,27,28	V <sub>D3</sub>	Drain biases for stage 3 of the amplifier. External bypass capacitors, de-Q resistors and bead inductors are required as described in the applications schematic. There is no internal connection between pins 14 and 23 and 28 so all pins need to be externally connected to the same voltage.
15,26	$V_{D4}$	Drain biases for stage 4 of the amplifier. External bypass capacitors, de-Q resistors and bead inductors are required as described in the applications schematic. There is no internal connection between pins 15 and 26 so both pins need to be externally connected to the same voltage.
19	V <sub>DET</sub>	Detector Diode Output voltage. This provides an output voltage proportional to the RF output power.
21	RF <sub>OUT</sub>	RF Signal Output. This pad is matched to 50 $\Omega$ and is AC coupled
29	$V_{D2}$	Drain bias for stage 2 of the amplifier. External bypass capacitors, de-Q resistor and bead inductor are required as described in the applications schematic.
31	V <sub>D1</sub>	Drain bias for stage 1 of the amplifier. External bypass capacitors, de-Q resistor and bead inductor are required as described in the applications schematic.



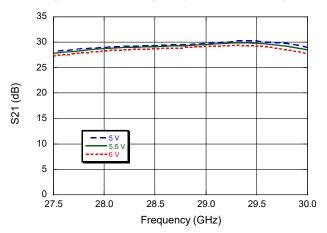
Rev. V1

## Typical Performance Curves: V<sub>D</sub> = 5.5 V, I<sub>DSQ</sub> = 1200 mA

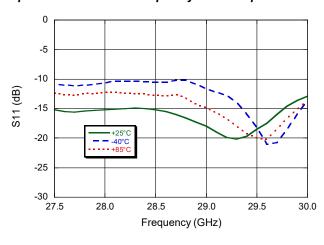
#### Small Signal Gain vs. Frequency over Temperature



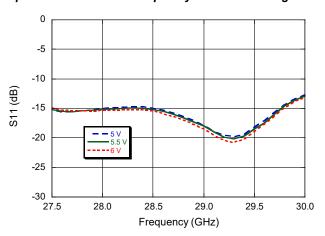
#### Small Signal Gain vs. Frequency over Bias Voltage



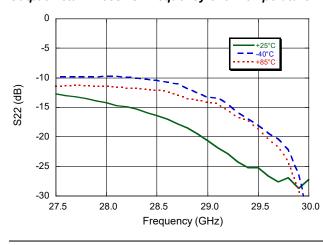
#### Input Return Loss vs. Frequency over Temperature



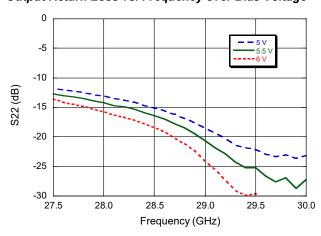
Input Return Loss vs. Frequency over Bias Voltage



#### Output Return Loss vs. Frequency over Temperature



#### Output Return Loss vs. Frequency over Bias Voltage



MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.

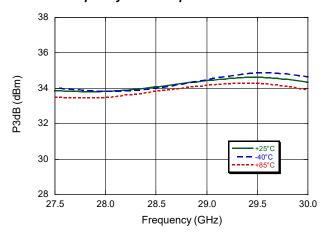
Visit <a href="https://www.macom.com">www.macom.com</a> for additional data sheets and product information.



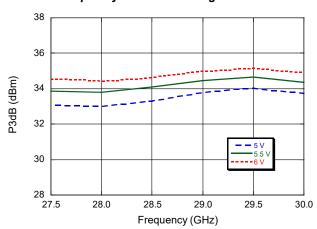
MAAP-011362 Rev. V1

# Typical Performance Curves: $V_D = 5.5 \text{ V}$ , $I_{DSQ} = 1200 \text{ mA}$

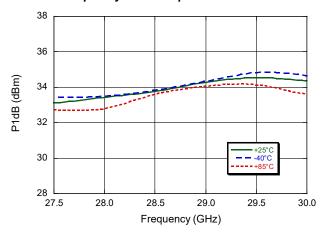
P3dB vs. Frequency over Temperature



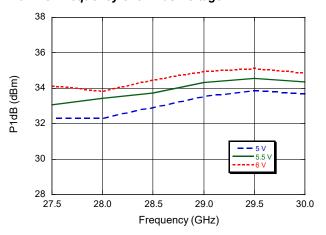
P3dB vs. Frequency over Bias Voltage



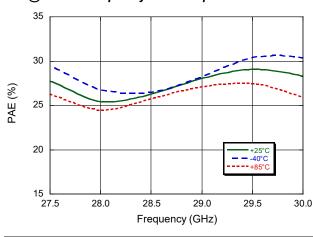
P1dB vs. Frequency over Temperature



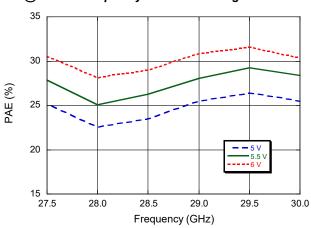
P1dB vs. Frequency over Bias Voltage



PAE@3dB vs. Frequency over Temperature



PAE@3dB vs. Frequency over Bias Voltage



MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.

Visit <a href="https://www.macom.com">www.macom.com</a> for additional data sheets and product information.

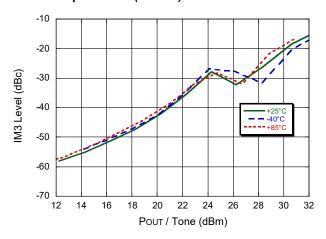
8



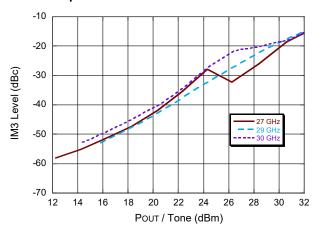
Rev. V1

# Typical Performance Curves: V<sub>D</sub> = 5.5 V, I<sub>DSQ</sub> = 1200 mA

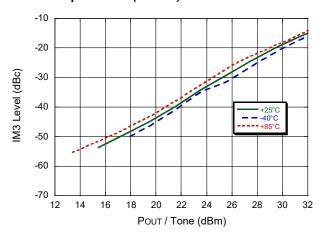
## IM3 vs. Output Power (27 GHz)



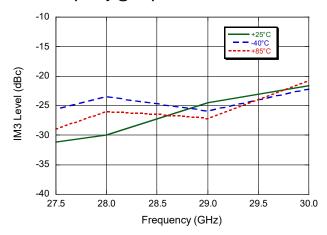
#### IM3 vs. Output Power



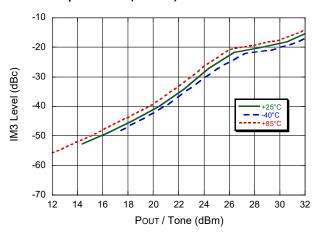
#### IM3 vs. Output Power (29 GHz)



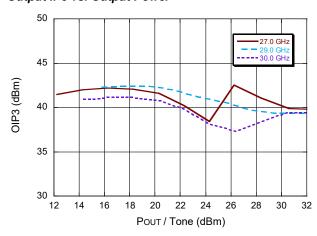
#### IM3 vs. Frequency @ Output Power = 27 dBm/tone



#### IM3 vs. Output Power (30 GHz)



#### Output IP3 vs. Output Power



9

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.

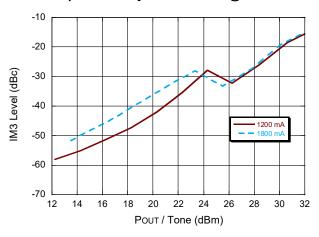
Visit <a href="https://www.macom.com">www.macom.com</a> for additional data sheets and product information.



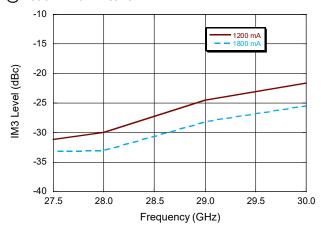
Rev. V1

## Typical Performance Curves: V<sub>D</sub> = 5.5 V, 25°C

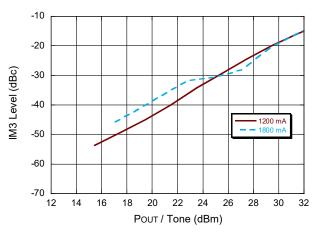
IM3 vs. Output Power by Drain Current @ 27 GHz



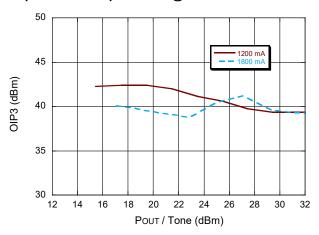
IM3 vs. Frequency by Drain Current
@ Pout = 27 dBm/tone



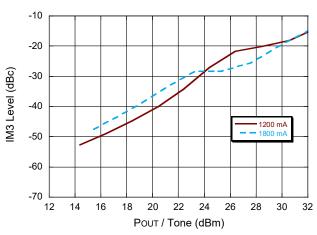
IM3 vs. Output Power by Drain Current @ 29 GHz



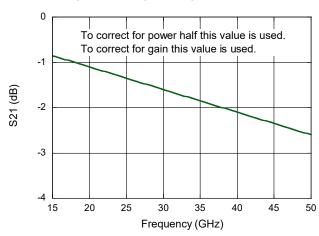
Output IP3 vs. Output Power @ 29 GHz



IM3 vs. Output Power by Drain Current @ 30 GHz



Combined Input and Output Sample Board Thru Loss



10

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice.

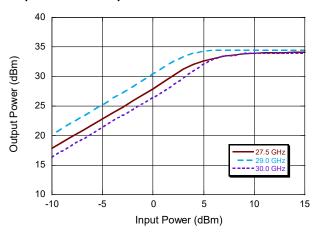
Visit <a href="https://www.macom.com">www.macom.com</a> for additional data sheets and product information.



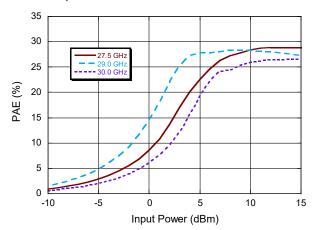
Rev. V1

## Typical Performance Curves: V<sub>D</sub> = 5.5 V, I<sub>DSQ</sub> = 1200 mA, +25°C

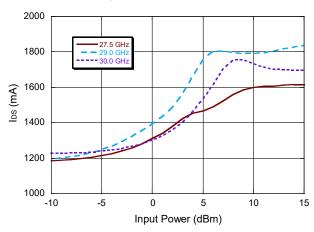
## Output Power vs. Input Power



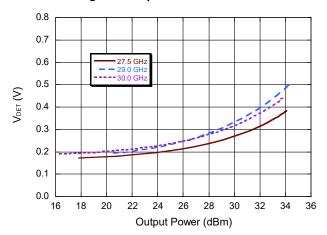
## PAE vs. Input Power



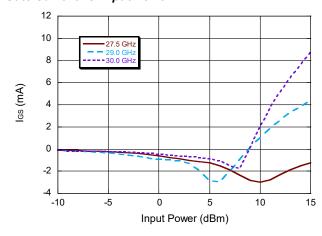
## Bias Current vs. Input Power



## Detector Voltage vs. Output Power



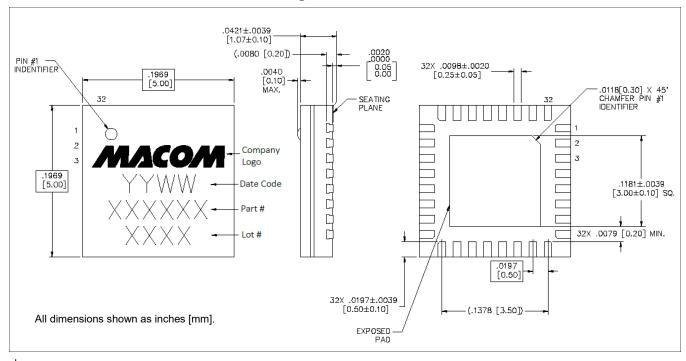
## Gate Current vs. Input Power





Rev. V1

# Lead-Free 5 mm 32-Lead AQFN Package<sup>†</sup>



Reference Application Note S2083 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 3 requirements. Plating is NiPdAu.

# Power Amplifier, 2 W 27.5 - 30.0 GHz



MAAP-011362

Rev. V1

## MACOM Technology Solutions Inc. ("MACOM"). All rights reserved.

These materials are provided in connection with MACOM's products as a service to its customers and may be used for informational purposes only. Except as provided in its Terms and Conditions of Sale or any separate agreement, MACOM assumes no liability or responsibility whatsoever, including for (i) errors or omissions in these materials; (ii) failure to update these materials; or (iii) conflicts or incompatibilities arising from future changes to specifications and product descriptions, which MACOM may make at any time, without notice. These materials grant no license, express or implied, to any intellectual property rights.

THESE MATERIALS ARE PROVIDED "AS IS" WITH NO WARRANTY OR LIABILITY, EXPRESS OR IMPLIED, RELATING TO SALE AND/OR USE OF MACOM PRODUCTS INCLUDING FITNESS FOR A PARTICULAR PURPOSE, MERCHANTABILITY, INFRINGEMENT OF INTELLECTUAL PROPERTY RIGHT, ACCURACY OR COMPLETENESS, OR SPECIAL, INDIRECT, INCIDENTAL, OR CONSEQUENTIAL DAMAGES WHICH MAY RESULT FROM USE OF THESE MATERIALS.

MACOM products are not intended for use in medical, lifesaving or life sustaining applications. MACOM customers using or selling MACOM products for use in such applications do so at their own risk and agree to fully indemnify MACOM for any damages resulting from such improper use or sale.